

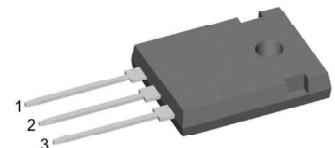
# Thyristor

$V_{RRM}$  = 1600 V  
 $I_{TAV}$  = 45 A  
 $V_T$  = 1,37 V

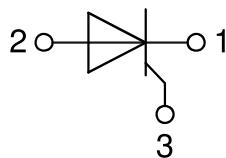
## Single Thyristor

### Part number

**CS45-16io1**



Backside: anode



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Terms & Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you.

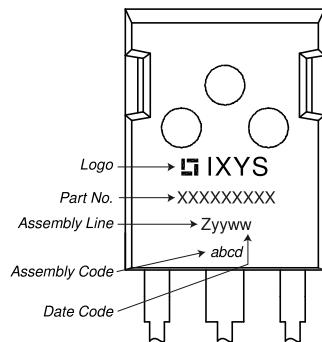
Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;
- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Thyristor			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1700	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1600	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 1600 \text{ V}$ $V_{R/D} = 1600 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		50 3	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 45 \text{ A}$ $I_T = 90 \text{ A}$ $I_T = 45 \text{ A}$ $I_T = 90 \text{ A}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1,36 1,73 1,37 1,85	V V V V
$I_{TAV}$	average forward current	$T_C = 110^\circ C$	$T_{VJ} = 150^\circ C$		45	A
$I_{T(RMS)}$	RMS forward current	180° sine			71	A
$V_{TO}$ $r_T$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ C$		0,88 11	V $m\Omega$
$R_{thJC}$	thermal resistance junction to case				0,4	K/W
$R_{thCH}$	thermal resistance case to heatsink			0,25		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		310	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ C$ $V_R = 0 \text{ V}$		520 560 440 475	A A A A
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ C$ $V_R = 0 \text{ V}$		1,35 1,31 970 940	kA <sup>2</sup> s kA <sup>2</sup> s A <sup>2</sup> s A <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	22		pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$ $t_p = 300 \mu s$	$T_C = 150^\circ C$		10 5 0,5	W W W
$P_{GAV}$	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 125^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 135 \text{ A}$ $t_p = 200 \mu s; di_G/dt = 0,3 \text{ A}/\mu s;$ $I_G = 0,3 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 45 \text{ A}$			150	A/ $\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$T_{VJ} = 125^\circ C$		1000	V/ $\mu s$
$V_{GT}$	gate trigger voltage	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		1,5 1,6	V V
$I_{GT}$	gate trigger current	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		80 200	mA mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^\circ C$		0,2	V
$I_{GD}$	gate non-trigger current				10	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0,3 \text{ A}; di_G/dt = 0,3 \text{ A}/\mu s$	$T_{VJ} = 25^\circ C$		150	mA
$I_H$	holding current	$V_D = 6 \text{ V}$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		100	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0,3 \text{ A}; di_G/dt = 0,3 \text{ A}/\mu s$	$T_{VJ} = 25^\circ C$		2	$\mu s$
$t_q$	turn-off time	$V_R = 100 \text{ V}; I_T = 45 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ C$ $di/dt = 15 \text{ A}/\mu s$ $dv/dt = 20 \text{ V}/\mu s$ $t_p = 200 \mu s$		150		$\mu s$

**Package TO-247**

<b>Symbol</b>	<b>Definition</b>	<b>Conditions</b>	<b>Ratings</b>			
			min.	typ.	max.	Unit
$I_{RMS}$	<i>RMS current</i>	per terminal			70	A
$T_{VJ}$	<i>virtual junction temperature</i>		-40		150	°C
$T_{op}$	<i>operation temperature</i>		-40		125	°C
$T_{stg}$	<i>storage temperature</i>		-40		150	°C
<b>Weight</b>				6		g
$M_d$	<i>mounting torque</i>		0,8		1,2	Nm
$F_c$	<i>mounting force with clip</i>		20		120	N

**Product Marking**

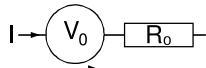
<b>Ordering</b>	<b>Ordering Number</b>	<b>Marking on Product</b>	<b>Delivery Mode</b>	<b>Quantity</b>	<b>Code No.</b>
Standard	CS45-16io1	CS45-16io1	Tube	30	467693

<b>Similar Part</b>	<b>Package</b>	<b>Voltage class</b>
CS45-08io1	TO-247AD (3)	800
CS45-12io1	TO-247AD (3)	1200
CS45-16io1R	ISOPLUS247 (3)	1600

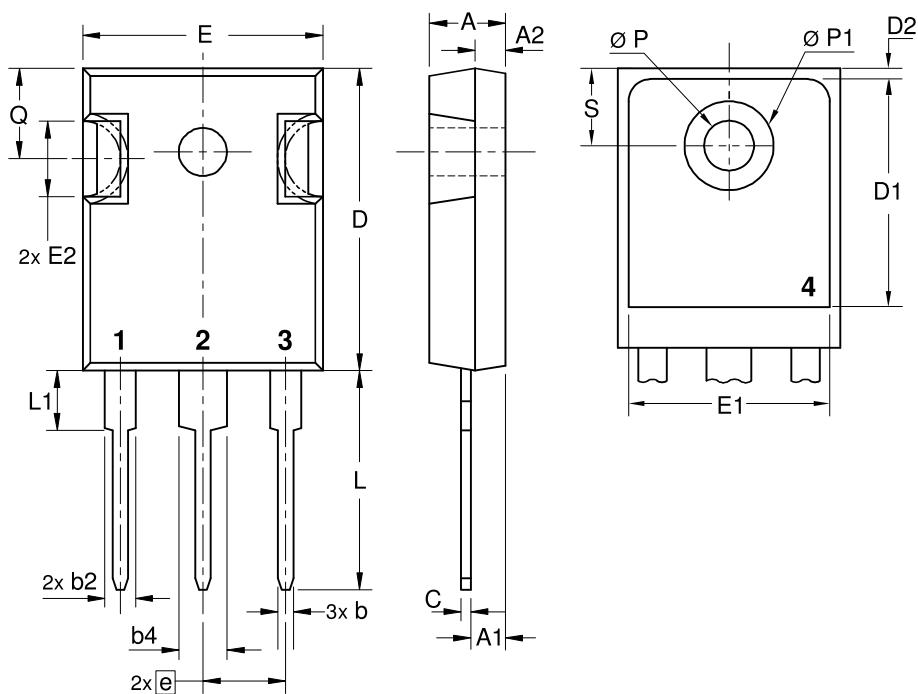
**Equivalent Circuits for Simulation**

\* on die level

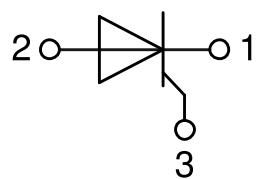
 $T_{VJ} = 150 \text{ }^{\circ}\text{C}$ 

	Thyristor
$V_{0\max}$	threshold voltage 0,88 V
$R_{0\max}$	slope resistance * 8,5 mΩ

## Outlines TO-247



Sym.	Inches min. max.	Millimeter min. max.
A	0.185 0.209	4.70 5.30
A1	0.087 0.102	2.21 2.59
A2	0.059 0.098	1.50 2.49
D	0.819 0.845	20.79 21.45
E	0.610 0.640	15.48 16.24
E2	0.170 0.216	4.31 5.48
e	0.215 BSC	5.46 BSC
L	0.780 0.800	19.80 20.30
L1	- 0.177	- 4.49
Ø P	0.140 0.144	3.55 3.65
Q	0.212 0.244	5.38 6.19
S	0.242 BSC	6.14 BSC
b	0.039 0.055	0.99 1.40
b2	0.065 0.094	1.65 2.39
b4	0.102 0.135	2.59 3.43
c	0.015 0.035	0.38 0.89
D1	0.515 -	13.07 -
D2	0.020 0.053	0.51 1.35
E1	0.530 -	13.45 -
Ø P1	- 0.29	- 7.39



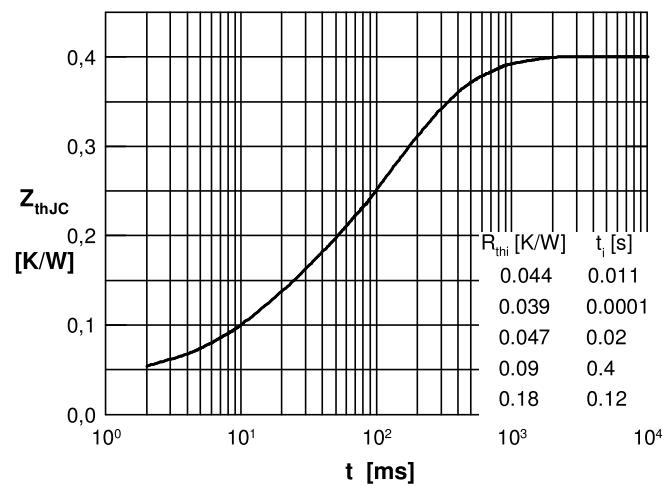
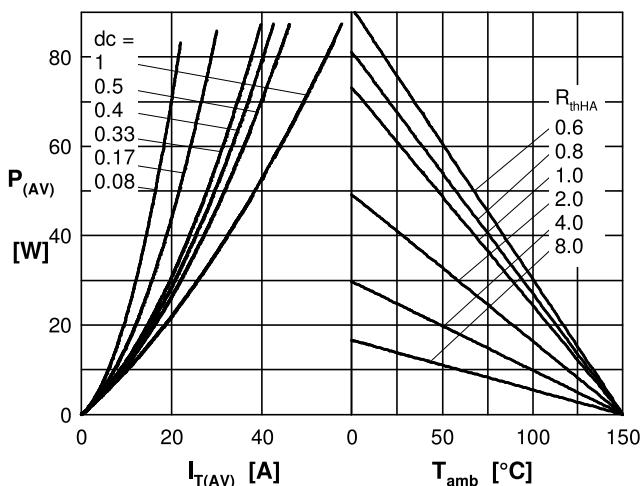
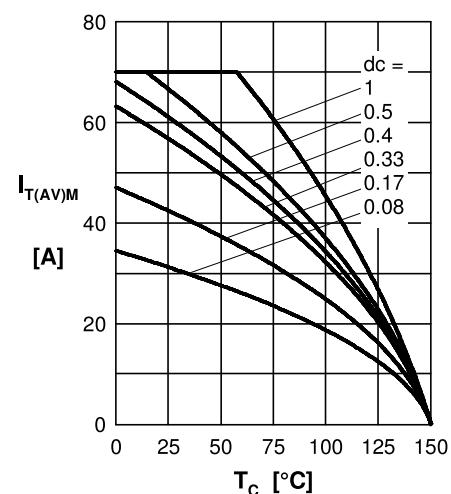
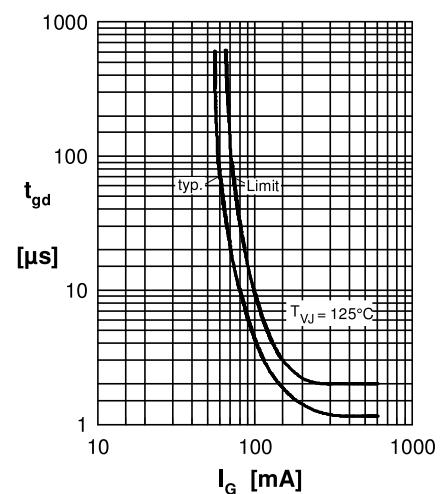
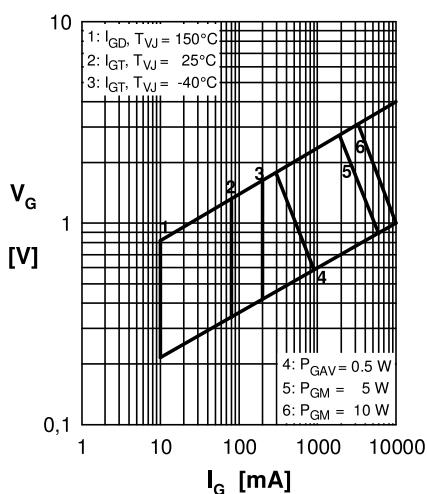
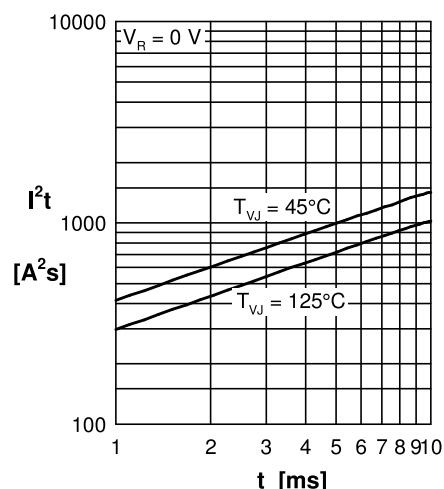
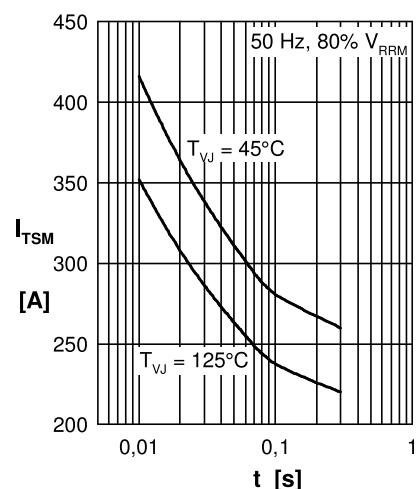
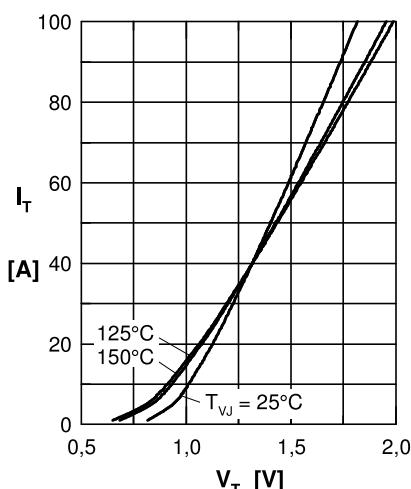
**Thyristor**

Fig. 7a Power dissipation versus direct output current  
Fig. 7b Power dissipation versus ambient temperature

Fig. 8 Transient thermal impedance junction to case